

HAC RF TESTREPORT

No.I17Z60885-SEM02

for

TCL Communication Ltd.

LTE / UMTS / GSM mobile phone

Model Name: 6058A

with

Hardware Version: PIO

Software Version: v2CT4

FCC ID: 2ACCJH078



Note:

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REPORT HISTORY

Report Number	Revision	Issue Date	Description	
I17Z60885-SEM02	Rev.0	2017-7-14	Initial creation of test report	
I17Z60885-SEM02	Rev.1	2017-7-25	Update the conclusion in section 10.3	
117200003-3610102	Rev. i	2017-7-25	on page 19	



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1 Test Laboratory

1.1 Testing Location

CompanyName:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25°C,			
Relative humidity:	30%~ 70%			
Ground system resistance:	< 0.5 Ω			
A selection of the sele				

Ambient noise is checked and found very low and in compliance with requirement of standards.

Reflection of surrounding objects is minimized and in compliance with requirement of standards.

1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Hao
Testing Start Date:	June 16, 2017
Testing End Date:	June 16, 2017

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

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2 Client Information

2.1 Applicant Information

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Telephone:	0086-21- 31363544		
Fax:	0086-21-61460602		



3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

3.1 About EUT

Description:	LTE / UMTS / GSM mobile phone
Model name:	6058A
Operating mode(s):	GSM 850/900/1800/1900, WCDMA 850/900/1700/1900/2100
	BT, Wi-Fi, LTE Band 1/2/3/4/5/7/12/13/17/28

3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	358472080201238	PIO	v2CT4
EUT2	358472080201105	PIO	v2CT4

^{*}EUT ID: is used to identify the test sample in the lab internally.

Note: It is performed to test HAC with the EUT1 and conducted power with the EUT2.

3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	CAC2710004C1	1	BYD
AE2	Battery	CAC2710005CC	1	JINNENG
AE3	Headset	CCB0049A10C4	1	MEIHAO
AE4	Headset	CCB0049A10C1	1	Juwei

^{*}AE ID: is used to identify the test sample in the lab internally.

Note: It is performed to test HAC with the AE2.

3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/tested	Simultaneous Transmissions	отт	Power Reduction
GSM	850	vo	Yes			NA
	1900			BT, WLAN	NA	147 (
GPRS/EDGE	850	DT	NA	DI, WLAN		No
GI KO/LDGL	1900	וטו	INA			
	850					
WCDMA	1700	VO	Yes	BT, WLAN	NA	NA
(UMTS)	1900					
	HSPA	DT	NA			
LTE	Band 2/4/5/7/12/13/17	V/D.	NA	BT, WLAN	NA	NA
BT	2450	DT	NA	GSM, WCDMA, LTE	NA	NA
WLAN	2450	DT	NA	GSM, WCDMA, LTE	NA	NA

VO: Voice CMRS/PSTN Service Only V/D: Voice CMRS/PSTN and Data Service DT: Digital Transport

Note:1.= No Associated T-Coil measurement has been made in accordance with 285076 D02 T-Coil testing for CMRS IP

^{*} HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



4 CONDUCTED OUTPUT POWER MEASUREMENT

4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

4.2 Conducted Power

CCM		Conducted Power (dBm)			
GSM 850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)		
830WI112	32.27	32.35	32.28		
0014	Conducted Power(dBm)				
GSM 1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)		
THUUNINZ	28.90	28.91	29.00		
MCDMA		Conducted Power (dBm)			
WCDMA	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)		
850MHz	22.44	22.52	22.38		
WCDMA		Conducted Power (dBm)			
WCDMA	Channel 1513 (1752.6MHz)	Channel 1412 (1732.4MHz)	Channel 1312 (1712.4MHz)		
1700MHz	22.68	22.58	22.68		
MCDMA		Conducted Power (dBm)			
WCDMA	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)		
1900MHz	22.91	22.99	22.80		
LTE		Conducted Power (dBm)			
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)		
QPSK	22.96	23.03	23.13		
LTE		Conducted Power (dBm)			
Band4	Channel 20300(1745MHz)	Channel20175(1732.5MHz)	Channel 20050(1720MHz)		
QPSK	23.40	23.29	23.28		
LTE		Conducted Power (dBm)			
Band5	Channel 20600(844MHz)	Channel20525(836.5MHz)	Channel 20450(829MHz)		
QPSK	21.97	21.96	22.18		
LTE		Conducted Power (dBm)			
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)		
QPSK	23.38	22.99	23.15		
LTE	Conducted Power (dBm)				
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)		
QPSK	22.54	22.60	22.55		
LTE	Conducted Power (dBm)				
Band13	Channel 23230(782MHz)				
QPSK		22.50			



LTE		Conducted Power (dBm)				
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)			
16-QAM	22.29	22.59	22.43			
LTE		Conducted Power (dBm)				
Band4	Channel 20300(1745MHz)	Channel20175(1732.5MHz)	Channel 20050(1720MHz)			
16-QAM	22.63	22.82	22.55			
LTE		Conducted Power (dBm)				
Band5	Channel 20600(844MHz)	Channel20525(836.5MHz)	Channel 20450(829MHz)			
16-QAM	20.93	20.97	21.42			
LTE		Conducted Power (dBm)				
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)			
16-QAM	22.48	22.51	22.41			
LTE		Conducted Power (dBm)				
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)			
16-QAM	22.17	21.67	22.17			
LTE	Conducted Power (dBm)					
Band13	Channel 23230(782MHz)					
16-QAM	21.51					

5 Reference Documents

5.1 Reference Documents for testing

The following document listed in this section is referred for testing.

_		
Reference	Title	Version
ANSI C63.19-2011	American National Standard for Methods of Measurement of	2011
	Compatibility between Wireless Communication Devices and	Edition
	Hearing Aids	
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets	2015
		Edition
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid Compatibility	



6 OPERATIONAL CONDITIONS DURING TEST

6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick),and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core21.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

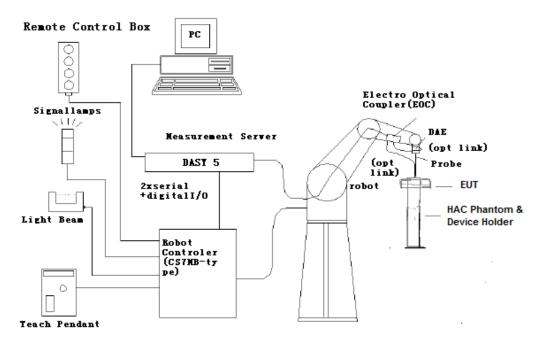


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



6.2 Probe Specification

E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity ± 0.2 dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms



[ER3DV6]



6.3Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: $370 \times 370 \times 370 \text{ mm}$).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.

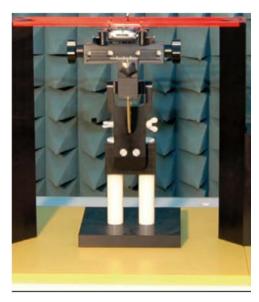


Fig. 2 HAC Phantom & Device Holder

6.4Robotic System Specifications

Specifications

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

Data Acquisition Electronic (DAE) System

Cell Controller

Processor: Intel Core2 Clock Speed: 1.86GHz

Operating System: Windows XP

Data Converter

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock



7 EUT ARRANGEMENT

7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

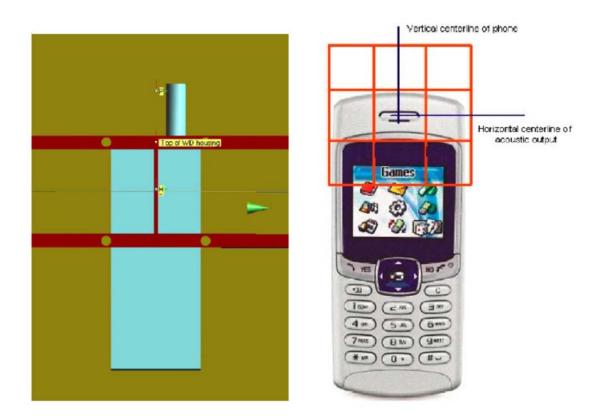


Fig. 3 WD reference and plane for RF emission measurements



8 SYSTEM VALIDATION

8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical output. Position the E-field probes so that:

- •The probes and their cables are parallel to the coaxial feed of the dipole antenna
- •The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 15 mm from the closest surface of the dipole elements.

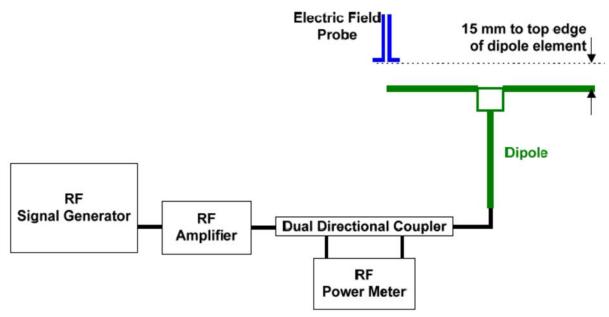


Fig. 4 Dipole Validation Setup

8.2 Validation Result

	E-Field Scan						
Mode	Mode Frequency Input Power Measured¹ Target² Deviation³ Limit⁴						
	(MHz)	(mW)	Value(dBV/m)	Value(dBV/m)	(%)	(%)	
CW	835	100	40.55	40.54	0.12	±25	
CW	1880	100	39.29	39.35	-0.69	±25	

Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within \pm 25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.



9 Evaluation of MIF

9.1 Introduction

The MIF (Modulation Interference Factor) is used to classify E-field emission to determine Hearing Aid Compatibility (HAC). It scales the power-averaged signal to the RF audio interference level and is characteristic to a modulation scheme. The HAC standard preferred "indirect" measurement method is based on average field measurement with separate scaling by the MIF. With an Audio Interference Analyzer (AIA) designed by SPEAG specifically for the MIF measurement, these values have been verified by practical measurements on an RF signal modulated with each of the waveforms. The resulting deviations from the simulated values are within the requirements of the HAC standard.

The AIA (Audio Interference Analyzer) is an USB powered electronic sensor to evaluate signals in the frequency range 698MHz - 6 GHz. It contains RMS detector and audio frequency circuits for sampling of the RF envelope.

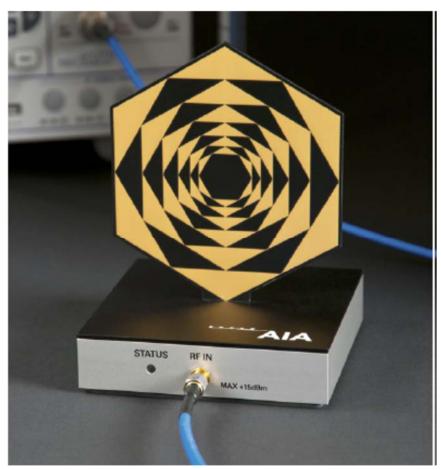


Fig. 5 AIA Front View



9.2 MIF measurement with the AIA

The MIF is measured with the AIA as follows:

- 1. Connect the AIA via USB to the DASY5 PC and verify the configuration settings.
- 2. Couple the RF signal to be evaluated to an AIA via cable or antenna.
- 3. Generate a MIF measurement job for the unknown signal and select the measurement port and timing settings.
- 4. Document the results via the post processor in a report.

9.3 Test equipment for the MIF measurement

No.	Name	Type	Serial Number	Manufacturer
01	Signal Generator	E4438C	MY49071430	Agilent
02	AIA	SE UMS 170 CB	1029	SPEAG
03	BTS	E5515C	MY50263375	Agilent

9.4 Test signal validation

The signal generator (E4438C) is used to generate a 1GHz signal with different modulation in the below table based on the ANSI C63.19-2011. The measured MIF with AIA are compared with the target values given in ANSI C63.19-2011 table D.3, D.4 and D5.

Pulse modulation	Target MIF	Measured MIF	Deviation
0.5ms pulse, 1000Hz repetition rate	-0.9 dB	-0.9 dB	0 dB
1ms pulse, 100Hz repetition rate	+3.9 dB	+3.7 dB	0.2 dB
0.1ms pulse, 100Hz repetition rate	+10.1 dB	+10.0 dB	0.1 dB
10ms pulse, 10Hz repetition rate	+1.6 dB	+1.7 dB	0.1 dB
Sine-wave modulation	Target MIF	Measured MIF	Deviation
1 kHz, 80% AM	-1.2 dB	-1.3 dB	0.1 dB
1 kHz, 10% AM	-9.1 dB	-9.0 dB	0.1 dB
1 kHz, 1% AM	-19.1 dB	-18.9 dB	0.2 dB
100 Hz, 10% AM	-16.1 dB	-16.0 dB	0.1 dB
10 kHz, 10% AM	-21.5 dB	-21.6 dB	0.1 dB
Transmission protocol	Target MIF	Measured MIF	Deviation
GSM; full-rate version 2; speech codec/handset low	+3.5 dB	+3.47 dB	0.03 dB
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB	-19.8 dB	0.2 dB
CDMA; speech; SO3; RC3; full frame rate; 8kEVRC	-19.0 dB	-19.1 dB	0.1 dB
CDMA; speech; SO3; RC1; 1/8 th frame rate; 8kEVRC	+3.3 dB	+3.44 dB	0.14 dB



9.5 DUT MIF results

Typical MIF levels in ANSI C63.19-2011				
Transmission protocol	Modulation interference factor			
GSM; full-rate version 2; speech codec/handset low	+3.5 dB			
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, QPSK)	-15.63 dB			
LTE-FDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-9.76 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, QPSK)	-1.62 dB			
LTE-TDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-1.44 dB			

Up Antenna

	Measured MIF lev	els
Band	Channel	Modulation interference factor
	251	3.44
GSM 850	190	3.48
	128	3.47
	4233	-25.47
WCDMA 850	4182	-22.60
	4132	-24.25
LTE Band5	20600	-14.69
QPSK —	20525	-14.82
QFSK	20450	-13.76
LTE Band12	23130	-14.54
QPSK —	23095	-14.59
QFSK	23060	-14.34
LTE Band13 QPSK	23230	-14.34
LTC Dands	20600	-9.51
LTE Band5 — 16QAM —	20525	-9.16
IOQAIVI	20450	-10.26
LTE Band12	23130	-9.96
16QAM	23095	-9.44
IOQAIVI	23060	-9.95
LTE Band13 16QAM	23230	-9.70



Up Antenna

	Measured MIF lev	
Band	Channel	Modulation interference factor
	251	3.49
GSM 850	190	3.50
	128	3.49
	810	3.43
GSM 1900	661	3.41
	512	3.47
	4233	-24.16
WCDMA 850	4182	-25.60
	4132	-24.33
	1513	-21.12
WCDMA 1700	1412	-19.89
	1312	-20.3
	9538	-21.45
WCDMA 1900	9400	-21.98
	9262	-20.9
	19100	-14.34
LTE Band2	18900	-14.73
QPSK —	18700	-14.34
	20300	-14.18
LTE Band4	20175	-14.10
QPSK —	20050	-13.82
	20600	-14.74
LTE Band5	20525	-14.98
QPSK —	20450	-15.24
	21350	-14.00
LTE Band7	21100	-14.32
QPSK —	20850	-14.50
	23130	-14.59
LTE Band12	23095	-14.70
QPSK —	23060	-14.76
LTE Band13 QPSK	23230	-14.53
Qi Oit	19100	-10.28
LTE Band2	18900	-10.20
16QAM —	18700	-9.77
	20300	-9.77
LTE Band4	20175	-10.40
16QAM	20050	-10.07
	20600	-9.99
LTE Band5	20525	-10.21
16QAM	20450	-9.68
	21350	-9.06
LTE Band7	21100	-9.93
16QAM —	20850	-10.74
LTE Band12	23130	-9.68 40.34
16QAM —	23095	-10.31
	23060	-10.79
LTE Band13 16QAM	23230	-9.63



10 Evaluation for low-power exemption

10.1 Product testing threshold

There are two methods for exempting an RF air interface technology from testing. The first method requires evaluation of the MIF for the worst-case operating mode. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is \leq 17 dBm for any of its operating modes. The second method does not require determination of the MIF. The RF emissions testing exemption shall be applied to an RF air interface technology in a device whose peak antenna input power, averaged over intervals \leq 50 μ s20, is \leq 23 dBm. An RF air interface technology that is exempted from testing by either method shall be rated as M4. The first method is used to be exempt from testing for the RF air interface technology in this report.

10.2 Conducted power

Up Antenna

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	32.35	3.48	35.83
WCDMA 850	22.52	-22.6	-0.08

Down Antenna

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	32.35	3.5	35.85
GSM 1900	29	3.47	32.47
WCDMA 850	22.44	-24.16	-1.72
WCDMA 1700	22.58	-19.89	2.69
WCDMA 1900	22.8	-20.9	1.9

10.3 Conclusion

According to the above table, the sums of average power and MIF for UMTS are less than 17dBm. So it is measured for GSM bands. The UMTS bands are exempt from testing and rated as M4.



11 RF TEST PROCEDUERES

The evaluation was performed with the following procedure:

- 1) Confirm proper operation of the field probe, probe measurement system and other instrumentation and the positioning system.
- 2) Position the WD in its intended test position. The gauge block can simplify this positioning.
- 3) Configure the WD normal operation for maximum rated RF output power, at the desired channel and other operating parameters (e.g., test mode), as intended for the test.
- 4) The center sub-grid shall centered on the center of the T-Coil mode axial measurement point or the acoustic output, as appropriate. Locate the field probe at the initial test position in the50 mm by 50 mm grid, which is contained in the measurement plane. If the field alignment method is used, align the probe for maximum field reception.
- 5) Record the reading.
- 6) Scan the entire 50 mm by 50 mm region in equally spaced increments and record the reading at each measurement point. The distance between measurement points shall be sufficient to assure the identification of the maximum reading.
- 7) Identify the five contiguous sub-grids around the center sub-grid whose maximum reading is the lowest of all available choices. This eliminates the three sub-grids with the maximum readings. Thus, the six areas to be used to determine the WD's highest emissions are identified.
- 8) Identify the maximum field reading within the non-excluded sub-grids identified in Step 7)
- 9) Evaluate the MIF and add to the maximum steady-state rms field-strength reading to obtain the RF audio interference level..
- Compare this RF audio interference level with the categories and record the resulting WD category rating.



12 Measurement Results (E-Field)

Up Antenna

Frequency		Measured	Dower Drift (dD)	Cotogory		
MHz	Channel	Value(dBV/m)	Power Drift (dB)	Category		
	GSM 850					
848.8	251	29.71	0.06	M4 (see Fig B.1)		
836.6	190	30.16	0.05	M4 (see Fig B.2)		
824.2	128	30.21	-0.01	M4 (see Fig B.3)		

Down Antenna

Freq	luency	Measured	Dower Drift (dD)	Catamany		
MHz	Channel	Value(dBV/m)	Power Drift (dB)	Category		
	GSM 850					
848.8	251	41.45	-0.00	M3 (see Fig B.4)		
836.6	190	41.99	-0.08	M3 (see Fig B.5)		
824.2	128	42.47	-0.03	M3 (see Fig B.6)		
	GSM 1900					
1909.8	810	17.7	-0.07	M4 (see Fig B.7)		
1880	661	17.51	-0.1	M4 (see Fig B.8)		
1850.2	512	21.68	-0.08	M4 (see Fig B.9)		

13 ANSIC 63.19-2011 LIMITS

WD RF audio interference level categories in logarithmic units

Emission categories	< 960 MHz				
	E-field e	E-field emissions			
Category M1	50 to 55	dB (V/m)			
Category M2	45 to 50	dB (V/m)			
Category M3	40 to 45	dB (V/m)			
Category M4	< 40	dB (V/m)			
Emission categories	>960	MHz			
	E-field e	E-field emissions			
Category M1	40 to 45	dB (V/m)			
Category M2	35 to 40	dB (V/m)			
Category M3	30 to 35	dB (V/m)			
Category M4	< 30	dB (V/m)			



14 MEASUREMENT UNCERTAINTY

No.	Error source	Туре	Uncertainty Value(%)	Prob. Dist.	k	c _i E	Standard Uncertainty (%) $u_i^{'}$ (%)E	Degree of freedom V _{eff} or <i>v</i> _i
	surement System			T		Π		T
1	Probe Calibration	В	5.	N	1	1	5.1	∞
2	Axial Isotropy	В	4.7	R	$\sqrt{3}$	1	2.7	∞
3	Sensor Displacement	В	16.5	R	$\sqrt{3}$	1	9.5	∞
4	Boundary Effects	В	2.4	R	$\sqrt{3}$	1	1.4	∞
5	Linearity	В	4.7	R	$\sqrt{3}$	1	2.7	∞
6	Scaling to Peak Envelope Power	В	2.0	R	$\sqrt{3}$	1	1.2	∞
7	System Detection Limit	В	1.0	R	$\sqrt{3}$	1	0.6	∞
8	Readout Electronics	В	0.3	N	1	1	0.3	∞
9	Response Time	В	0.8	R	$\sqrt{3}$	1	0.5	∞
10	Integration Time	В	2.6	R	$\sqrt{3}$	1	1.5	∞
11	RF Ambient Conditions	В	3.0	R	$\sqrt{3}$	1	1.7	∞
12	RF Reflections	В	12.0	R	$\sqrt{3}$	1	6.9	∞
13	Probe Positioner	В	1.2	R	$\sqrt{3}$	1	0.7	∞
14	Probe Positioning	А	4.7	R	$\sqrt{3}$	1	2.7	∞
15	Extra. And Interpolation	В	1.0	R	$\sqrt{3}$	1	0.6	∞
Test	Test Sample Related							
16	Device Positioning Vertical	В	4.7	R	$\sqrt{3}$	1	2.7	∞
17	Device Positioning Lateral	В	1.0	R	$\sqrt{3}$	1	0.6	∞
18	Device Holder and Phantom	В	2.4	R	$\sqrt{3}$	1	1.4	∞
19	Power Drift	В	5.0	R	$\sqrt{3}$	1	2.9	∞



20	AIA measurement	В	12	R	$\sqrt{3}$	1	6.9	∞
Pha	Phantom and Setup related							
21	Phantom Thickness	В	2.4	R	$\sqrt{3}$	1	1.4	∞
Coml	Combined standard uncertainty(%) 16.2							
	nded uncertainty idence interval of 95 %)	u	$u_e = 2u_c$	N	k=:	2	32.4	

15 MAIN TEST INSTRUMENTS

Table 1: List of Main Instruments

No.	Name	Туре	Serial Number	Calibration Date	Valid Period
01	Signal Generator	E4438C	MY49071430	January 13,2017	One Year
02	Power meter	NRVD	102083	Santambar 22 2016	One year
03	Power sensor	NRV-Z5	100595	September 22,2016	One year
04	Amplifier	60S1G4	0331848	No Calibration Re	quested
05	E-Field Probe	ER3DV6	2428	January 19, 2017	One year
06	HAC Dipole	CD835V3	1023	August 31, 2016	One year
07	HAC Dipole	CD1880V3	1018	August 31, 2016	One year
80	BTS	E5515C	MY50263375	January 16, 2017	One year
09	DAE	SPEAG DAE4	777	August 22, 2016	One year
10	AIA	SE UMS 170 CB	1029	No Calibration Re	quested

16 CONCLUSION

The HAC measurement indicates that the EUT complies with the HAC limits of the ANSIC63.19-2011. The total M-rating is **M3.**

END OF REPORT BODY



ANNEX A TEST LAYOUT



Picture A1:HAC RF System Layout



ANNEX B TEST PLOTS

HAC RF E-Field GSM 850 High Up ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM850/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

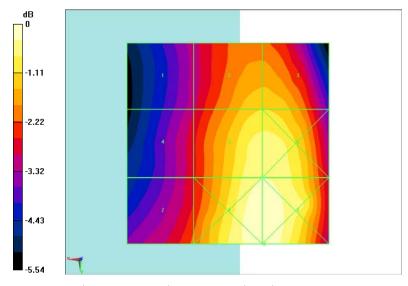
Reference Value = 23.93 V/m; Power Drift = 0.06 dB

Applied MIF = 3.44 dB

RF audio interference level = 29.71 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.08 dBV/m	28.97 dBV/m	28.97 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
27.45 dBV/m	29.71 dBV/m	29.71 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
28 dBV/m	30.07 dBV/m	30.08 dBV/m



0 dB = 31.92 V/m = 30.08 dBV/m

Fig B.1 HAC RF E-Field GSM 850 High



HAC RF E-Field GSM 850 Middle Up ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM850/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.43 V/m; Power Drift = 0.05 dB

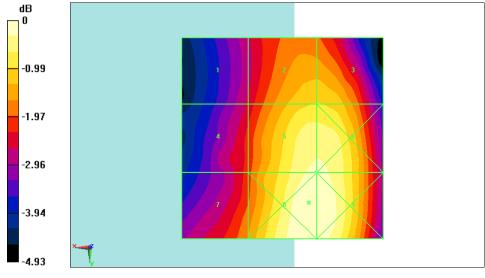
Applied MIF = 3.48 dB

RF audio interference level = 30.16 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.91 dBV/m	29.45 dBV/m	29.45 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
28.31 dBV/m	30.16 dBV/m	30.16 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
28.8 dBV/m	30.41 dBV/m	30.39 dBV/m



0 dB = 33.17 V/m = 30.41 dBV/m

Fig B.2 HAC RF E-Field GSM 850 Middle



HAC RF E-Field GSM 850 Low Up ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM850/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 25.95 V/m; Power Drift = -0.01 dB

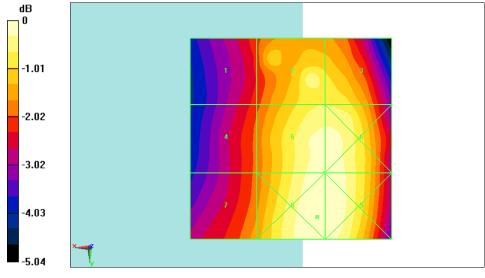
Applied MIF = 3.47 dB

RF audio interference level = 30.21 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
28.23 dBV/m	29.84 dBV/m	29.66 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
28.46 dBV/m	30.21 dBV/m	30.21 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
28.86 dBV/m	30.33 dBV/m	30.32 dBV/m



0 dB = 32.86 V/m = 30.33 dBV/m

Fig B.3 HAC RF E-Field GSM 850 Low



HAC RF E-Field GSM 850 High Down ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

GSM850/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

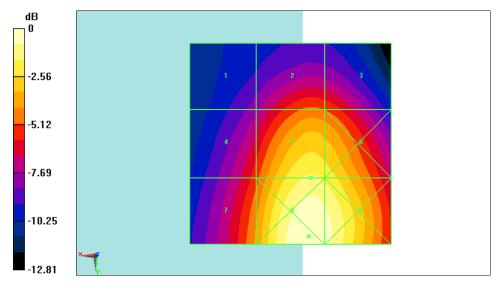
Reference Value = 102.3 V/m; Power Drift = -0.00 dB

Applied MIF = 3.49 dB

RF audio interference level = 41.45 dBV/m

Emission category: M3

Grid 2 M4 38.12 dBV/m	Grid 3 M4 37.87 dBV/m
Grid 5 M3 41.45 dBV/m	Grid 6 M3 41.12 dBV/m
Grid 8 M3	Grid 9 M3 42.55 dBV/m



0 dB = 141.3 V/m = 43.00 dBV/m

Fig B.4 HAC RF E-Field GSM 850 High



HAC RF E-Field GSM 850 Middle Down ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 836.6 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM850/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 111.4 V/m; Power Drift = -0.08 dB

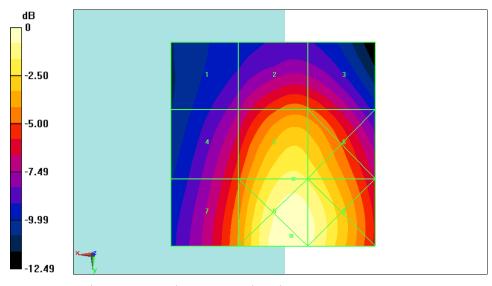
Applied MIF = 3.50 dB

RF audio interference level = 41.99 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
35.73 dBV/m	38.81 dBV/m	38.54 dBV/m
Grid 4 M4	Grid 5 M3	Grid 6 M3
38.15 dBV/m	41.99 dBV/m	41.61 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
39.28 dBV/m	43.34 dBV/m	42.89 dBV/m



0 dB = 146.9 V/m = 43.34 dBV/m

Fig B.5 HAC RF E-Field GSM 850 Middle



HAC RF E-Field GSM 850 Low Down ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM850/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

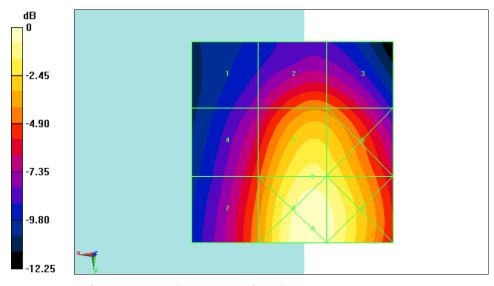
Reference Value = 119.1 V/m; Power Drift = -0.03 dB

Applied MIF = 3.49 dB

RF audio interference level = 42.47 dBV/m

Emission category: M3

Grid 1 M4	Grid 2 M4	Grid 3 M4
36.21 dBV/m	39.47 dBV/m	39.23 dBV/m
Grid 4 M4	Grid 5 M3	Grid 6 M3
38.6 dBV/m	42.47 dBV/m	42.16 dBV/m
Grid 7 M4	Grid 8 M3	Grid 9 M3
39.62 dBV/m	43.69 dBV/m	43.3 dBV/m



0 dB = 153.0 V/m = 43.69 dBV/m

Fig B.6 HAC RF E-Field GSM 850 Low



HAC RF E-Field GSM 1900 High Down ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM1900/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device/Hearing

Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 4.465 V/m; Power Drift = -0.07 dB

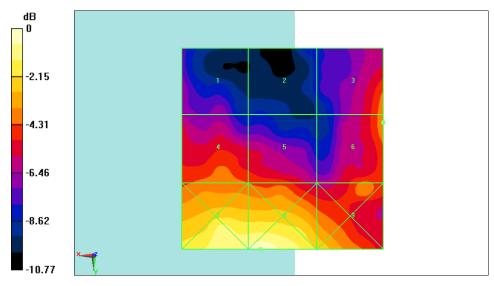
Applied MIF = 3.43 dB

RF audio interference level = 17.70 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
14.82 dBV/m	13.21 dBV/m	17.62 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
17.24 dBV/m	16.88 dBV/m	17.7 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
20.72 dBV/m	21.18 dBV/m	19 dBV/m



0 dB = 11.45 V/m = 21.18 dBV/m

Fig B.7 HAC RF E-Field GSM 1900 High



HAC RF E-Field GSM 1900 Middle Down ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM1900/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 2/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

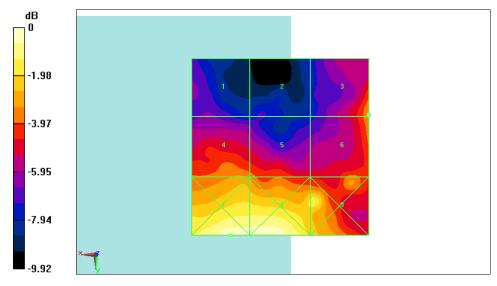
Reference Value = 4.587 V/m; Power Drift = -0.10 dB

Applied MIF = 3.41 dB

RF audio interference level = 17.51 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
14.29 dBV/m	13.48 dBV/m	17.51 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
17.46 dBV/m	17.14 dBV/m	17.5 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
20.63 dBV/m	20.57 dBV/m	19.08 dBV/m



0 dB = 10.75 V/m = 20.63 dBV/m

Fig B.8 HAC RF E-Field GSM 1900 Middle



HAC RF E-Field GSM 1900 Low Down ANT

Date: 2017-4-26

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Ambient Temperature: 22.0°C

Communication System: DCS 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

GSM1900/E Scan - ER3DV6 - 2011: 15 mm from Probe Center to the Device 3/Hearing Aid Compatibility Test (101x101x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

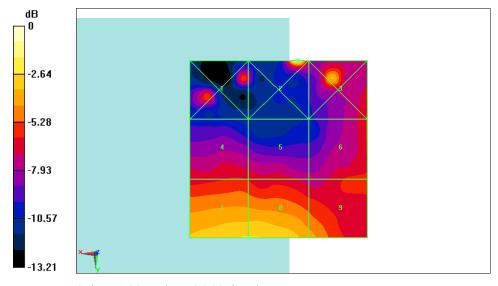
Reference Value = 4.528 V/m; Power Drift = -0.08 dB

Applied MIF = 3.47 dB

RF audio interference level = 21.68 dBV/m

Emission category: M4

Grid 1 M4	Grid 2 M4	Grid 3 M4
18.8 dBV/m	24.21 dBV/m	20.81 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
18.21 dBV/m	17.98 dBV/m	18.43 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
21.68 dBV/m	21.68 dBV/m	20.31 dBV/m



0 dB = 16.25 V/m = 24.22 dBV/m

Fig B.9 HAC RF E-Field GSM 1900 Low



ANNEX C SYSTEM VALIDATION RESULT

E SCAN of Dipole 835 MHz

Date: 2017-6-16

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon r = 1$; $\rho = 1000$ kg/m3 Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 15mm/Hearing Aid Compatibility Test (41x361x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

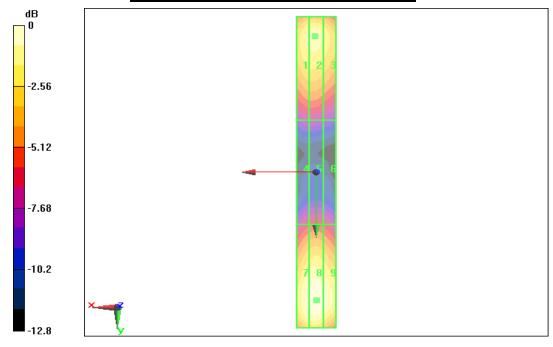
Reference Value = 105.9 V/m; Power Drift = -0.02 dB

Applied MIF = 0.00 dB

RF audio interference level = 40.55 dBV/m

Emission category: M3

Grid 2 M3 40.55 dBV/m	Grid 3 M3 40.39 dBV/m
Grid 5 M4 35.82dBV/m	Grid 6 M4 35.81 dBV/m
Grid 8 M3 40.23 dBV/m	Grid 9 M3 40.16 dBV/m



0 dB = 40.55 dBV/m



E SCAN of Dipole 1880 MHz

Date: 2017-6-16

Electronics: DAE4 Sn777

Medium: Air

Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Probe: ER3DV6 - SN2428;ConvF(1, 1, 1)

E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 15mm/Hearing Aid Compatibility Test (41x181x1): Interpolated grid: dx=0.5000 mm,

dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

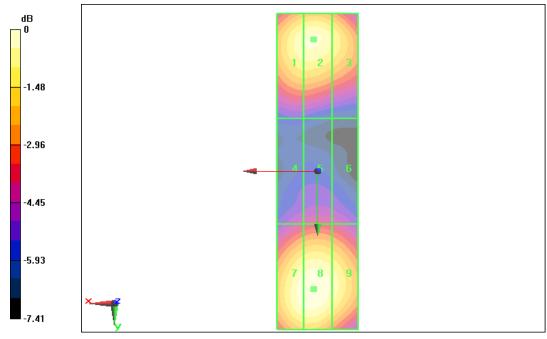
Reference Value = 94.1 V/m; Power Drift = -0.06 dB

Applied MIF = 0.00 dB

RF audio interference level = 39.35 dBV/m

Emission category: M2

Grid 1M2	Grid 2M2	Grid 3 M2
39.24 dBV/m	39.35 dBV/m	39.31 dBV/m
Grid 4M2	Grid 5M2	Grid 6M2
36.91 dBV/m	37.09 dBV/m	37.02 dBV/m
Grid 7M2	Grid 8M2	Grid 9 M2
39.27 dBV/m	39.33 dBV/m	39.31 dBV/m



0 dB = 39.35 dBV/m



ANNEX D PROBE CALIBRATION CERTIFICATE

E_Probe ER3DV6

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

CTTL (Auden)

Certificate No: ER3-2428_Jan17

CALIBRATION CERTIFICATE

ER3DV6 - SN:2428 Object

QA CAL-02.v8, QA CAL-25.v6 Calibration procedure(s)

Calibration procedure for E-field probes optimized for close near field

evaluations in air

January 19, 2017 Calibration date:

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

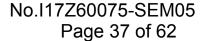
Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	06-Apr-16 (No. 217-02288/02289)	Apr-17
Power sensor NRP-Z91	SN: 103244	06-Apr-16 (No. 217-02288)	Apr-17
Power sensor NRP-Z91	SN: 103245	06-Apr-16 (No. 217-02289)	Apr-17
Reference 20 dB Attenuator	SN: S5277 (20x)	05-Apr-16 (No. 217-02293)	Apr-17
Reference Probe ER3DV6	SN: 2328	14-Oct-16 (No. ER3-2328_Oct16)	Oct-17
DAE4	SN: 789	11-Nov-16 (No. DAE4-789_Nov16)	Nov-17
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-16)	In house check: Jun-18
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-16)	In house check: Jun-18
Network Analyzer HP 8753E	SN: US37390585	18-Oct-01 (in house check Oct-16)	In house check: Oct-17

Name Function Laboratory Technician Calibrated by: Jeton Kastrati Katja Pokovic Technical Manager Approved by: Issued: January 21, 2017 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Page 1 of 10

Certificate No: ER3-2428_Jan17



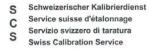


Calibration Laboratory of Schmid & Partner Engineering AG

Zeughausstrasse 43, 8004 Zurich, Switzerland







Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z sensitivity in free space diode compression point

CF crest factor (1/duty_cycle) of the RF signal A, B, C, D modulation dependent linearization parameters

Polarization φ rotation around probe axis

Polarization 9 9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

- IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005
- b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.0, November 2013

Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization θ = 0 for XY sensors and θ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open wavequide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).



January 19, 2017

Probe ER3DV6

SN:2428

Manufactured: Calibrated:

September 11, 2007 January 19, 2017

Calibrated for DASY/EASY Systems (Note: non-compatible with DASY2 system!)

Certificate No: ER3-2428_Jan17

Page 3 of 10



January 19, 2017

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2428

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (µV/(V/m) ²)	1.47	1.54	1.78	± 10.1 %
DCP (mV) ^B	98.8	98.8	99.7	AT 375

Modulation Calibration Parameters

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Unc ^t (k=2)
0	CW	X	0.0	0.0	1.0	0.00	203.6	±3.5 %
		Y	0.0	0.0	1.0		189.7	
		Z	0.0	0.0	1.0		198.1	
10011- CAB	UMTS-FDD (WCDMA)	X	3.12	65.9	18.2	2.91	120.0	±0.5 %
		Y	3.12	65.8	18.2		114.3	
		Z	3.15	66.1	18.1	i	116.8	
10021- DAC		×	21.68	99.3	28.7	9.39	133.5	±1.9 %
		Y	20.43	99.7	28.9		119.5	
		Z	25.63	99.4	28.4		143.4	
10039- CAB	CDMA2000 (1xRTT, RC1)	х	4.75	66.2	19.0	4.57	121.7	±0.9 %
		Y	4.78	66.5	19.1		115.3	
		Z	4.59	65.8	18.5		117.6	Page 1
10081- CDMA2000 (1xRTT, RC3)	Х	3.92	65.8	18.6	3.97	117.3	±0.7 %	
		Y	3.78	64.9	18.1		112.1	101
		Z	3.80	65.3	18.1		116.3	

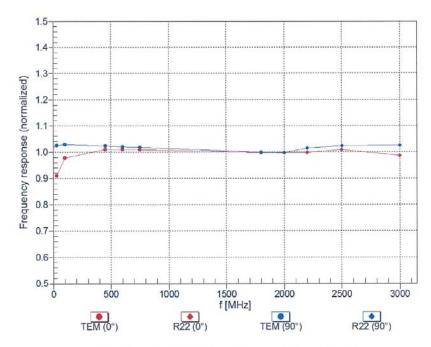
The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

B Numerical linearization parameter: uncertainty not required. E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.



ER3DV6 - SN:2428 January 19, 2017

Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)

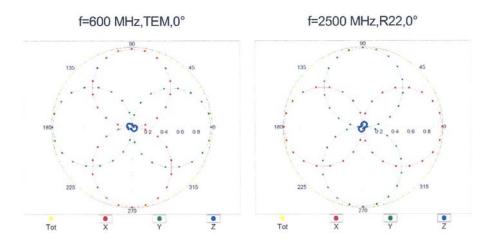


Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

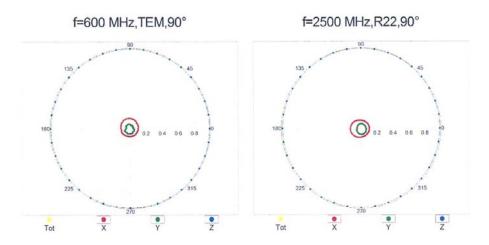


ER3DV6 – SN:2428 January 19, 2017

Receiving Pattern (ϕ), $9 = 0^{\circ}$



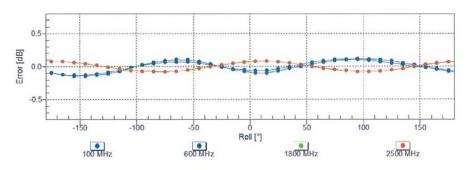
Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$





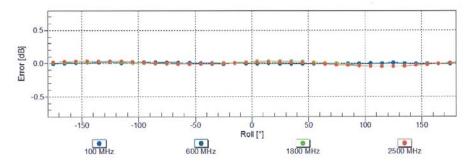
January 19, 2017

Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$

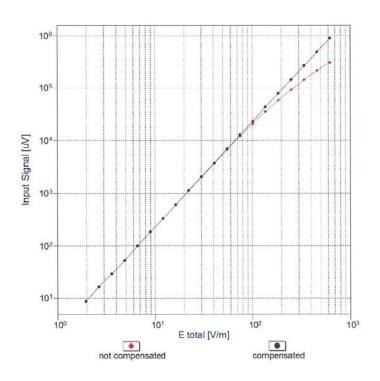


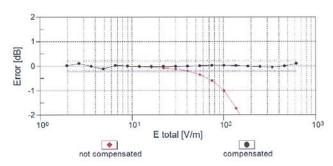
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)



ER3DV6 - SN:2428 January 19, 2017

Dynamic Range f(E-field) (TEM cell , f = 900 MHz)



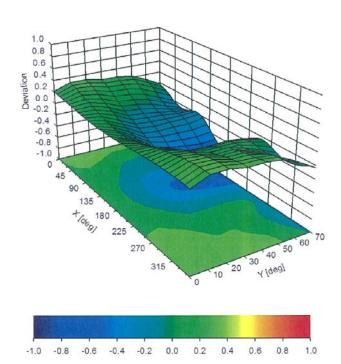


Uncertainty of Linearity Assessment: ± 0.6% (k=2)



ER3DV6 – SN:2428 January 19, 2017

Deviation from Isotropy in Air Error (ϕ , ϑ), f = 900 MHz



Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)



January 19, 2017

DASY/EASY - Parameters of Probe: ER3DV6 - SN:2428

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	144.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm



ANNEX E DIPOLE CALIBRATION CERTIFICATE

Dipole 835 MHz

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

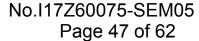
Client

CTTL-BJ (Auden)

Certificate No: CD835V3-1023 Aug16

Object	CD835V3 - SN: 1023		
Calibration procedure(s)	QA CAL-20.v6 Calibration proce	edure for dipoles in air	
Calibration date:	August 31, 2016		
This calibration certificate docum	ents the traceability to nat	ional standards, which realize the physical u	nits of measurements (SI).
		robability are given on the following pages a	
All calibrations have been conduc	cted in the closed laborato	ry facility: environment temperature (22 ± 3)	°C and humidity < 70%.
Calibration Equipment used (M&	TE critical for calibration)		
Primary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
			Scrieduled Calibration
Power meter NRP	SN: 104778	06-Apr-16 (No. 217-02288/02289)	Apr. 17
	SN: 104778 SN: 103244	06-Apr-16 (No. 217-02288/02289) 06-Apr-16 (No. 217-02288)	Apr-17
Power sensor NRP-Z91	SN: 103244	06-Apr-16 (No. 217-02288)	Apr-17
Power sensor NRP-Z91 Power sensor NRP-Z91	SN: 103244 SN: 103245	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289)	Apr-17 Apr-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator	SN: 103244	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292)	Apr-17 Apr-17 Apr-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination	SN: 103244 SN: 103245 SN: 5058 (20k)	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295)	Apr-17 Apr-17 Apr-17 Apr-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295)	Apr-17 Apr-17 Apr-17 Apr-17
Power meter NRP Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15) Check Date (in house)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16 Scheduled Check
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15) Check Date (in house) 09-Oct-09 (in house check Sep-14)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16 Scheduled Check In house check: Oct-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16 Scheduled Check In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15) Check Date (in house) 09-Oct-09 (in house check Sep-14) 05-Jan-10 (in house check Sep-14)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16 Scheduled Check In house check: Oct-17 In house check: Oct-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8753E	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US37390585 Name	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15) Check Date (in house) 09-Oct-09 (in house check Sep-14) 09-Oct-09 (in house check Sep-14) 27-Aug-12 (in house check Oct-15) 18-Oct-01 (in house check Oct-15) Function	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16 Scheduled Check In house check: Oct-17 In house check: Oct-17 In house check: Oct-17 In house check: Oct-17
Power sensor NRP-Z91 Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe ER3DV6 Probe H3DV6 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 103244 SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 2336 SN: 6065 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US37390585	06-Apr-16 (No. 217-02288) 06-Apr-16 (No. 217-02289) 05-Apr-16 (No. 217-02292) 05-Apr-16 (No. 217-02295) 31-Dec-15 (No. ER3-2336_Dec15) 31-Dec-15 (No. H3-6065_Dec15) 04-Sep-15 (No. DAE4-781_Sep15) Check Date (in house) 09-Oct-09 (in house check Sep-14) 09-Oct-09 (in house check Sep-14) 27-Aug-12 (in house check Oct-15) 18-Oct-01 (in house check Oct-15)	Apr-17 Apr-17 Apr-17 Apr-17 Dec-16 Dec-16 Sep-16 Scheduled Check In house check: Oct-17

Certificate No: CD835V3-1023_Aug16

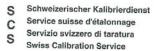




Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland







Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

References

- ANSI-C63.19-2007
 American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.
- [2] ANSI-C63.19-2011 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 10 mm (15 mm for [2]) above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1] and [2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (15 mm for [2]) (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
 antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field scan. The
 maximum of the field is available at the center (subgrid 5) above the feed point. The H-field value stated as
 calibration value represents the maximum of the interpolated H-field, 10mm above the dipole surface at the
 feed point.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: CD835V3-1023_Aug16 Page 2 of 8



Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.8.8
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	10, 15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

H-field 10 mm above dipole surface	condition	interpolated maximum	
Maximum measured	100 mW input power	0.450 A/m ± 8.2 % (k=2)	

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	166.0 V/m = 44.40 dBV/m
Maximum measured above low end	100 mW input power	159.9 V/m = 44.08 dBV/m
Averaged maximum above arm	100 mW input power	162.9 V/m ± 12.8 % (k=2)

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	106.4 V/m = 40.54 dBV/m
Maximum measured above low end	100 mW input power	104.5 V/m = 40.38 dBV/m
Averaged maximum above arm	100 mW input power	105.5 V/m ± 12.8 % (k=2)



Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	17.6 dB	40.9 Ω - 7.8 jΩ
835 MHz	24.6 dB	53.4 Ω + 5.0 jΩ
900 MHz	16.0 dB	52.5 Ω - 16.3 jΩ
950 MHz	21.8 dB	49.2 Ω + 8.0 jΩ
960 MHz	16.4 dB	60.1 Ω + 13.4 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

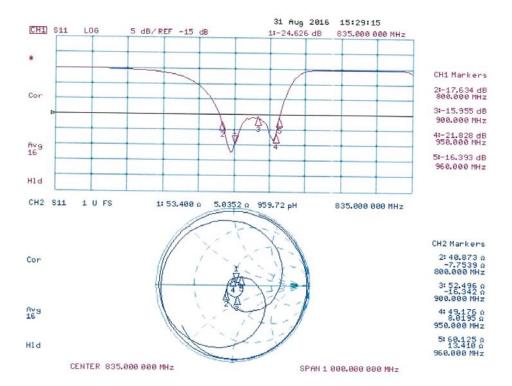
The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.



Impedance Measurement Plot





DASY5 H-field Result

Date: 31.08.2016

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1023

Communication System: UID 0 - CW; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

Probe: H3DV6 - SN6065; ; Calibrated: 31.12.2015

Sensor-Surface: (Fix Surface)

Electronics: DAE4 Sn781; Calibrated: 04.09.2015

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070

DASY52 52.8.8(1258); SEMCAD X 14.6.10(7372)

Dipole H-Field measurement @ 835MHz/H-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

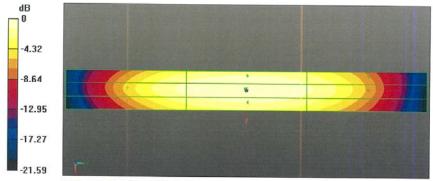
Reference Value = 0.4780 A/m; Power Drift = -0.01 dB

PMR not calibrated. PMF = 1.000 is applied.

H-field emissions = 0.4504 A/m Near-field category; M4 (AWF 0 dB)

PMF scaled H-field

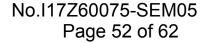
Grid 1 M4	Grid 2 M4	Grid 3 M4
0.370 A/m	0.405 A/m	0.391 A/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
0.415 A/m	0.450 A/m	0.438 A/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
0.364 A/m	0.395 A/m	0.384 A/m



0 dB = 0.4504 A/m = -6.93 dBA/m

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Certificate No: CD835V3-1023_Aug16





DASY5 E-field Result

Date: 31.08.2016

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: 1023

Communication System: UID 0 - CW ; Frequency: 835 MHz Medium parameters used: $\sigma=0$ S/m, $\epsilon_r=1$; $\rho=1000$ kg/m 3 Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

Probe: ER3DV6 - SN2336; ConvF(1, 1, 1); Calibrated: 31.12.2015;

Sensor-Surface: (Fix Surface)

Electronics: DAE4 Sn781; Calibrated: 04.09.2015

Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070

DASY52 52.8.8(1258); SEMCAD X 14.6.10(7372)

Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=10mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 108.1 V/m; Power Drift = -0.01 dB Applied MIF = 0.00 dB RF audio interference level = 44.40 dBV/m Emission category: M3

MIF scaled E-field

and the second	Grid 2 M3 44.08 dBV/m	Grid 3 M3 43.83 dBV/m
1	Grid 5 M4 38.79 dBV/m	Grid 6 M4 38.51 dBV/m
Grid 7 M3 43.98 dBV/m	Control of the Contro	Grid 9 M3 44.21 dBV/m

Certificate No: CD835V3-1023_Aug16